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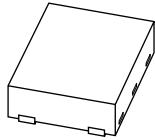
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Kind regards,

Team Nexperia



# PMEG2010EPA

1 A low  $V_F$  MEGA Schottky barrier rectifier

Rev. 01 — 15 December 2009

Product data sheet

## 1. Product profile

### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection. PMEG2010EPA is encapsulated in an ultra thin SOT1061 leadless small Surface-Mounted Device (SMD) plastic package with medium power capability.

### 1.2 Features

- Average forward current:  $I_{F(AV)} \leq 1 \text{ A}$
- Reverse voltage:  $V_R \leq 20 \text{ V}$
- Low forward voltage
- Exposed heat sink (cathode pad) for excellent thermal and electrical conductivity
- Leadless small SMD plastic package with medium power capability
- AEC-Q101 qualified

### 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications
- Battery chargers for mobile equipment

### 1.4 Quick reference data

**Table 1. Quick reference data**

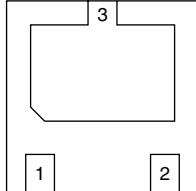
$T_j = 25^\circ\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{F(AV)}$	average forward current	square wave; $\delta = 0.5$ ;	$T_{amb} \leq 125^\circ\text{C}$	-	-	1
		$f = 20 \text{ kHz}$		-	-	A
		$T_{sp} \leq 145^\circ\text{C}$	-	-	1	A
$V_R$	reverse voltage		-	-	20	V
$V_F$	forward voltage	$I_F = 1 \text{ A}$	-	320	375	mV
$I_R$	reverse current	$V_R = 20 \text{ V}$	-	335	1900	$\mu\text{A}$

[1] Device mounted on a ceramic Printed-Circuit Board (PCB),  $\text{Al}_2\text{O}_3$ , standard footprint.

## 2. Pinning information

**Table 2. Pinning**

Pin	Description	Simplified outline	Graphic symbol
1	anode		
2	anode		
3	cathode	 Transparent top view	 006aab624

## 3. Ordering information

**Table 3. Ordering information**

Type number	Package			Version
	Name	Description		
PMEG2010EPA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; three terminals; body 2 × 2 × 0.65 mm		SOT1061

## 4. Marking

**Table 4. Marking codes**

Type number	Marking code
PMEG2010EPA	A1

## 5. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>R</sub>	reverse voltage	T <sub>j</sub> = 25 °C	-	20	V
I <sub>F(AV)</sub>	average forward current	square wave; δ = 0.5; f = 20 kHz	T <sub>amb</sub> ≤ 125 °C  T <sub>sp</sub> ≤ 145 °C	[1] -  - -	1 1 A
I <sub>FRM</sub>	repetitive peak forward current	t <sub>p</sub> ≤ 1 ms; δ ≤ 0.25	[2]	-	A
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; t <sub>p</sub> = 8 ms	[2][3]	-	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[4][5]  [4][6]  [4][1]	500 960 1800	mW mW mW

**Table 5. Limiting values ...continued**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

[2] Both anode pins connected.

[3] T<sub>j</sub> = 25 °C prior to surge.

[4] Reflow soldering is the only recommended soldering method.

[5] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[6] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

## 6. Thermal characteristics

**Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1][2]			
			[3]	-	-	250 K/W
			[4]	-	-	130 K/W
			[5]	-	-	70 K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		[6]	-	-	12 K/W

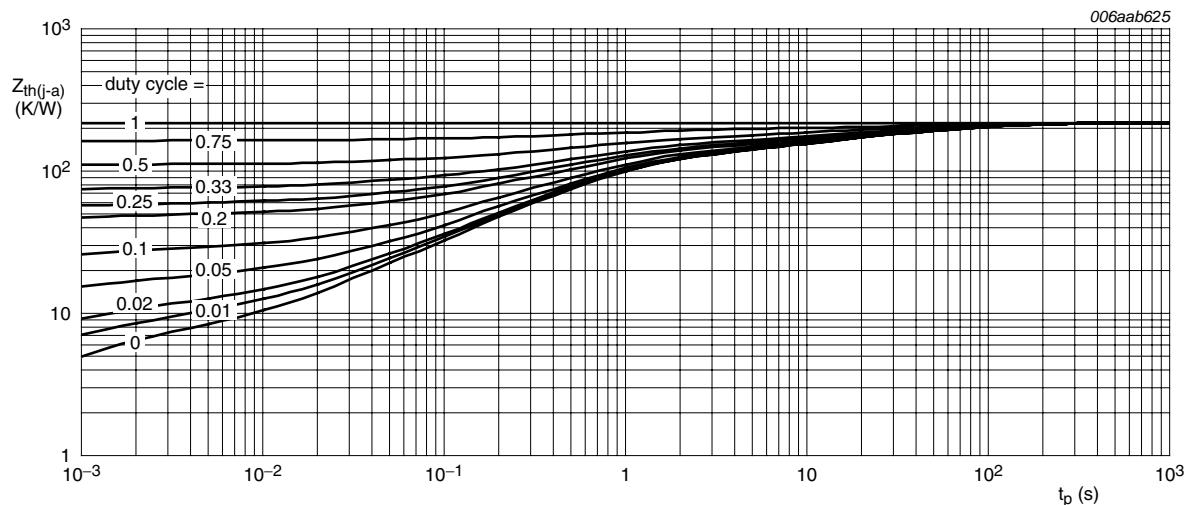
[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

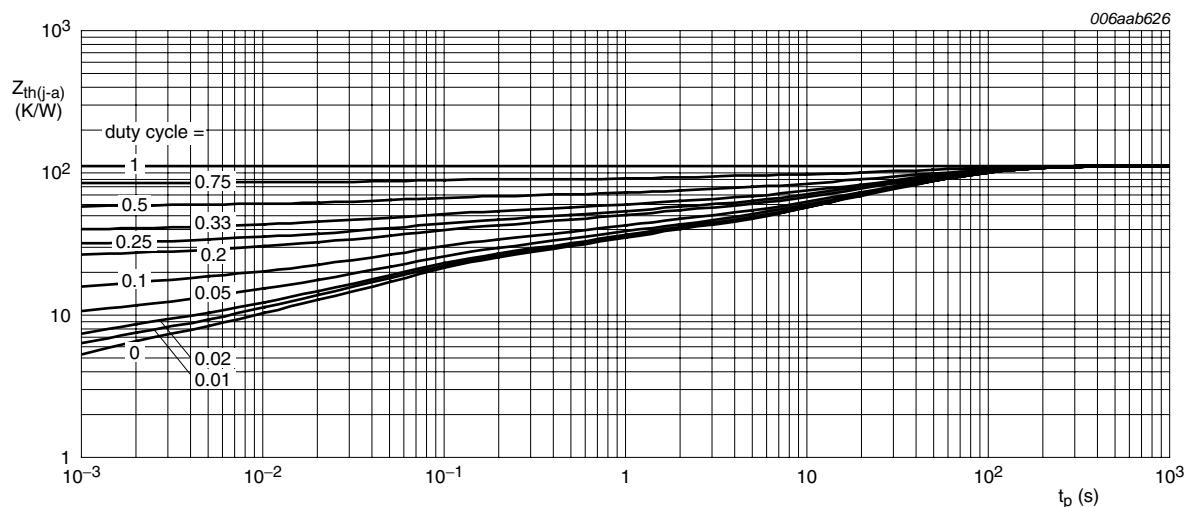
[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.[5] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

[6] Soldering point of cathode tab.



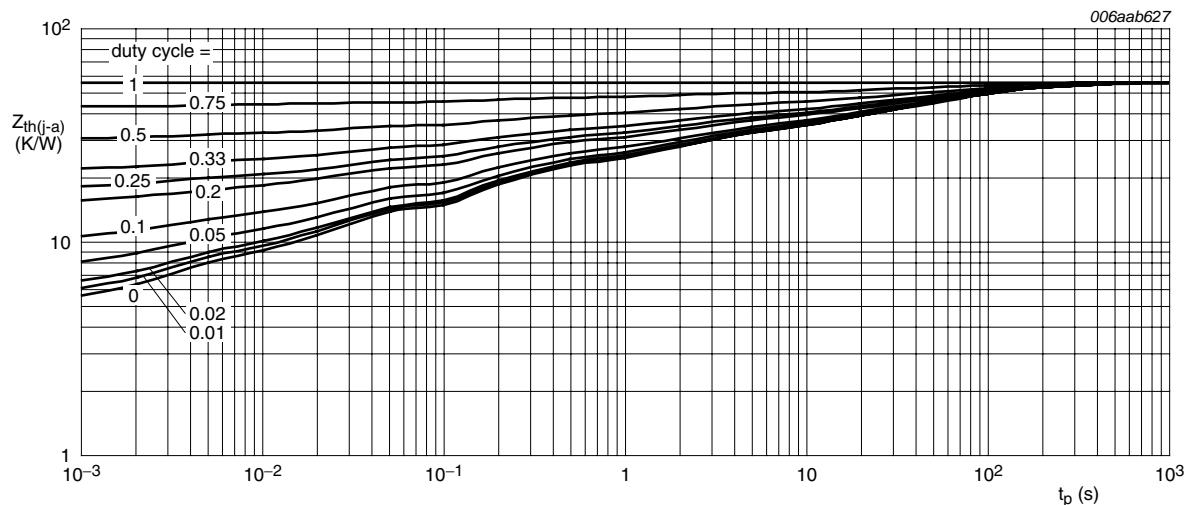
FR4 PCB, standard footprint

**Fig 1.** Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for cathode 1 cm<sup>2</sup>

**Fig 2.** Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB,  $\text{Al}_2\text{O}_3$ , standard footprint

**Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values**

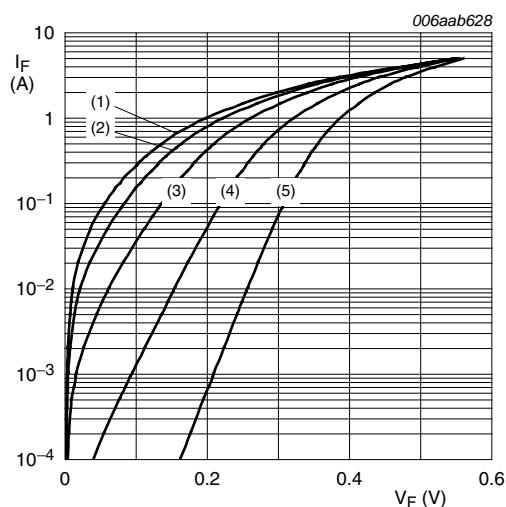
## 7. Characteristics

**Table 7. Characteristics**

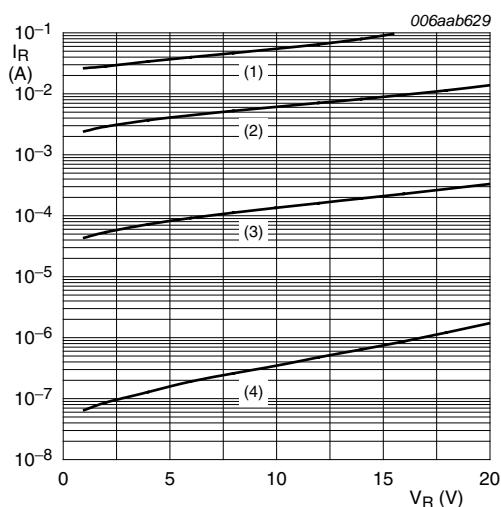
$T_j = 25^\circ\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_F$	forward voltage	$I_F = 0.5 \text{ A}$	-	280	-	mV
		$I_F = 1 \text{ A}$	-	320	375	mV
$I_R$	reverse current	$V_R = 10 \text{ V}$	-	135	-	$\mu\text{A}$
		$V_R = 20 \text{ V}$	-	335	1900	$\mu\text{A}$
$C_d$	diode capacitance	$f = 1 \text{ MHz}$				
		$V_R = 1 \text{ V}$	-	175	-	pF
		$V_R = 10 \text{ V}$	-	65	-	pF
$t_{rr}$	reverse recovery time	[1]	-	50	-	ns

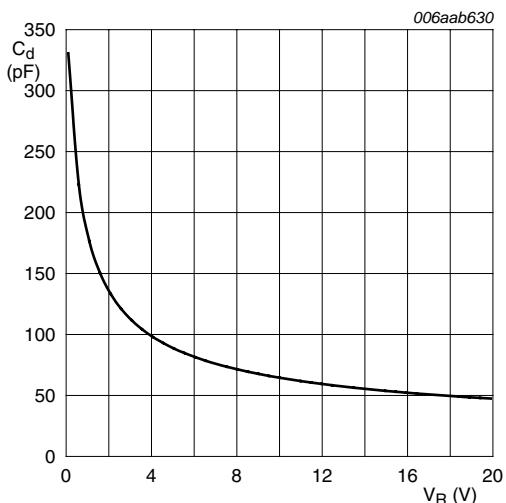
[1] When switched from  $I_F = 10 \text{ mA}$  to  $I_R = 10 \text{ mA}$ ;  $R_L = 100 \Omega$ ; measured at  $I_R = 1 \text{ mA}$ .



**Fig 4.** Forward current as a function of forward voltage; typical values

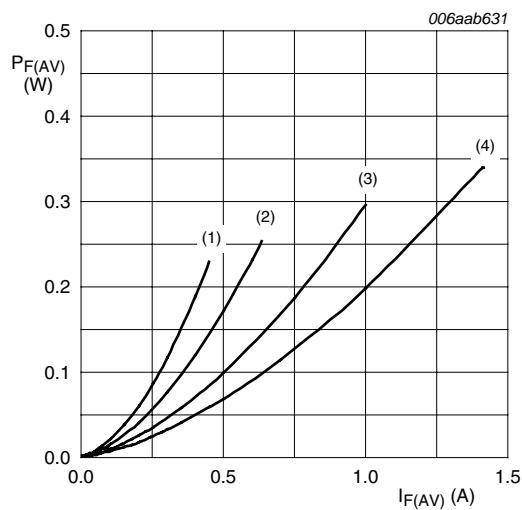


**Fig 5.** Reverse current as a function of reverse voltage; typical values



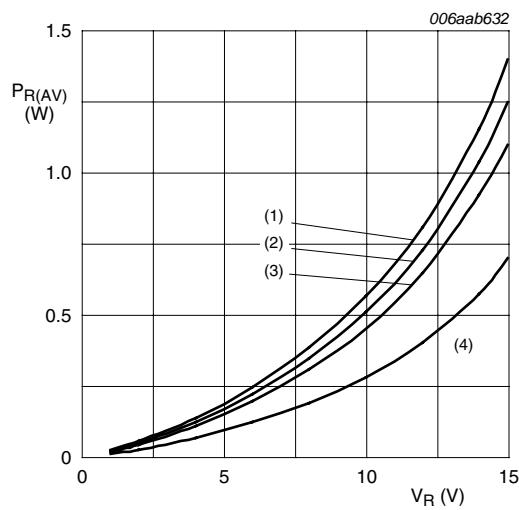
$f = 1$  MHz;  $T_{amb} = 25$  °C

**Fig 6.** Diode capacitance as a function of reverse voltage; typical values

 $T_j = 150^\circ\text{C}$ 

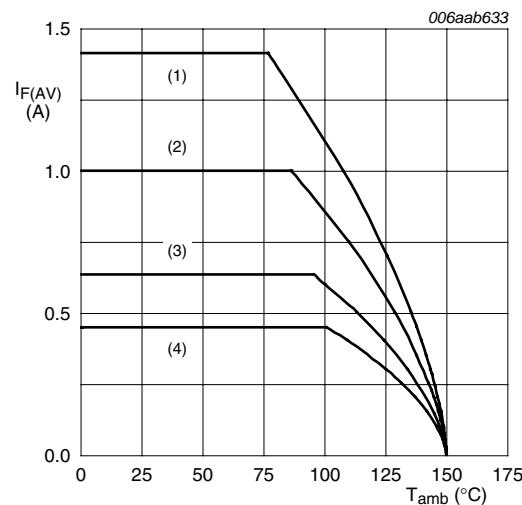
- (1)  $\delta = 0.1$
- (2)  $\delta = 0.2$
- (3)  $\delta = 0.5$
- (4)  $\delta = 1$

**Fig 7. Average forward power dissipation as a function of average forward current; typical values**

 $T_j = 125^\circ\text{C}$ 

- (1)  $\delta = 1$
- (2)  $\delta = 0.9$
- (3)  $\delta = 0.8$
- (4)  $\delta = 0.5$

**Fig 8. Average reverse power dissipation as a function of reverse voltage; typical values**

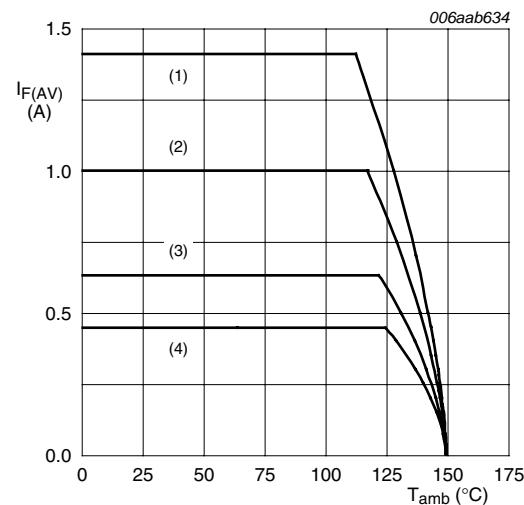


FR4 PCB, standard footprint

 $T_j = 150^\circ\text{C}$ 

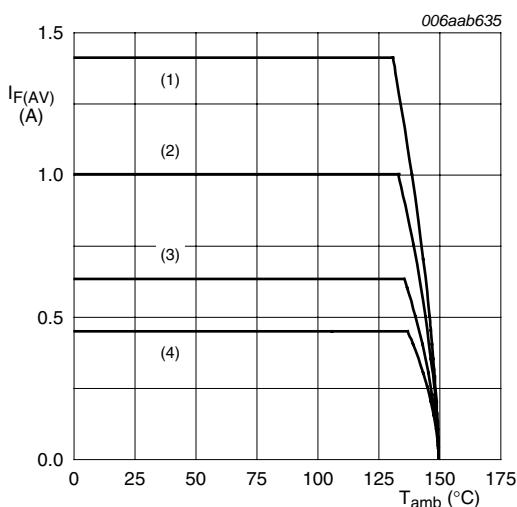
- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20$  kHz
- (3)  $\delta = 0.2$ ;  $f = 20$  kHz
- (4)  $\delta = 0.1$ ;  $f = 20$  kHz

**Fig 9. Average forward current as a function of ambient temperature; typical values**

FR4 PCB, mounting pad for cathode 1 cm<sup>2</sup> $T_j = 150^\circ\text{C}$ 

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20$  kHz
- (3)  $\delta = 0.2$ ;  $f = 20$  kHz
- (4)  $\delta = 0.1$ ;  $f = 20$  kHz

**Fig 10. Average forward current as a function of ambient temperature; typical values**

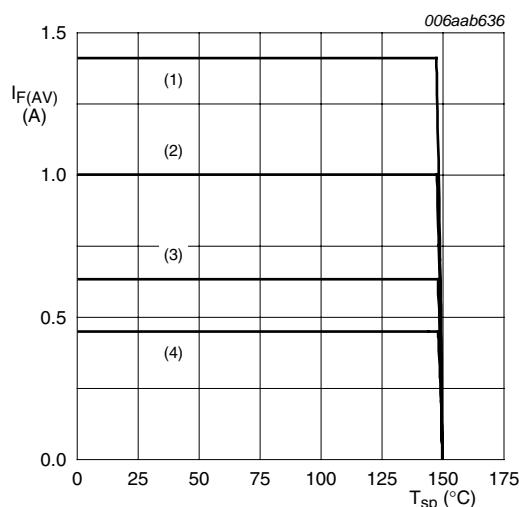


Ceramic PCB,  $\text{Al}_2\text{O}_3$ , standard footprint

$T_j = 150$  °C

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20$  kHz
- (3)  $\delta = 0.2$ ;  $f = 20$  kHz
- (4)  $\delta = 0.1$ ;  $f = 20$  kHz

**Fig 11. Average forward current as a function of ambient temperature; typical values**

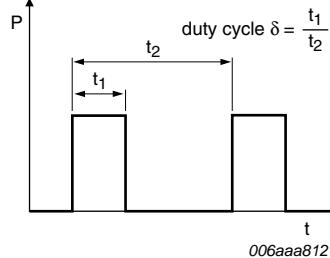


$T_j = 150$  °C

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20$  kHz
- (3)  $\delta = 0.2$ ;  $f = 20$  kHz
- (4)  $\delta = 0.1$ ;  $f = 20$  kHz

**Fig 12. Average forward current as a function of solder point temperature; typical values**

## 8. Test information



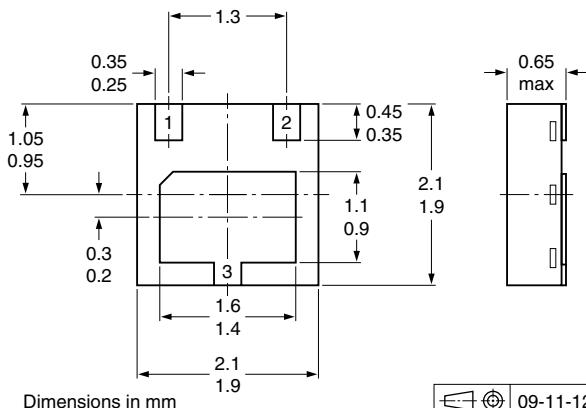
**Fig 13. Duty cycle definition**

The current ratings for the typical waveforms as shown in [Figure 9, 10, 11](#) and [12](#) are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,  $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



**Fig 14. Package outline SOT1061**

## 10. Packing information

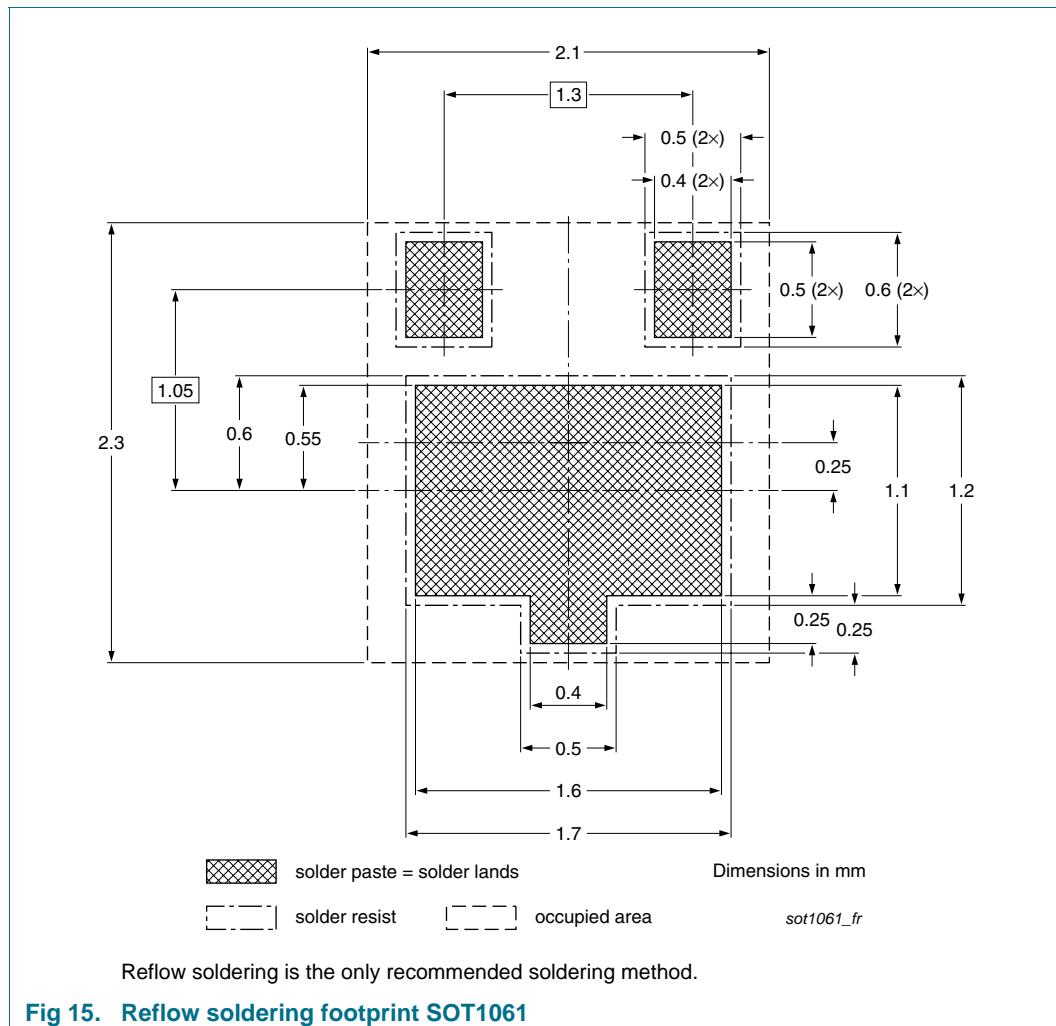
**Table 8.** Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[\[1\]](#)

Type number	Package	Description	Packing quantity
PMEG2010EPA	SOT1061	4 mm pitch, 8 mm tape and reel	3000 -115

[1] For further information and the availability of packing methods, see [Section 14](#).

## 11. Soldering



## 12. Revision history

**Table 9. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG2010EPA_1	20091215	Product data sheet	-	-

## 13. Legal information

### 13.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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